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HMC510* Product Page Quick Links

Last Content Update: 11/01/2016

Comparable Parts

View a parametric search of comparable parts

Evaluation Kits

- HMC510LP5 Evaluation Board.

Documentation

Data Sheet

- HMC510 Data Sheet

Reference Materials

Quality Documentation

- Package/Assembly Qualification Test Report: 32L 5x5mm QFN Package (QTR: 10009 REV: 05)
- Package/Assembly Qualification Test Report: LP3, LP4, LP5 & LP5G (QTR: 2014-00145)
- Package/Assembly Qualification Test Report: Plastic Encapsulated QFN (QTR: 05006 REV: 02)
- Semiconductor Qualification Test Report: GaAs HBT-A (QTR: 2013-00228)

Technical Articles

- High Performance SiGe PLLs Pair with Low Phase Noise GaAs VCOs for Microwave Radio

Design Resources

- HMC510 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

Discussions

View all HMC510 EngineerZone Discussions

Sample and Buy

Visit the product page to see pricing options

Technical Support

Submit a technical question or find your regional support number

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HMC510LP5/510LP5E

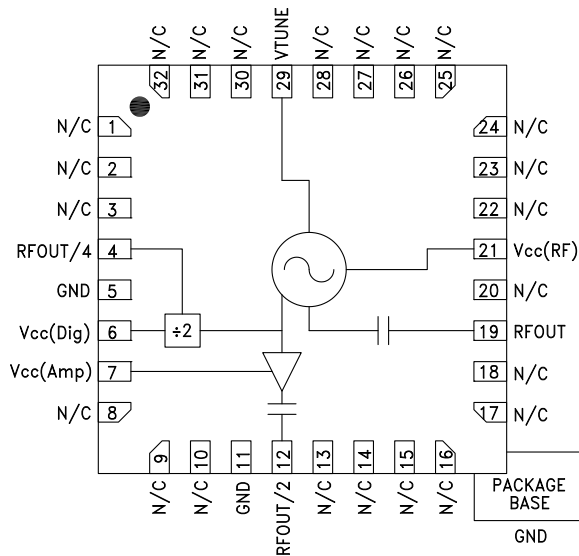
MMIC VCO WITH HALF FREQUENCY OUTPUT 8.45 - 9.55 GHz

Typical Applications

Low noise MMIC VCO w/Half Frequency, Divide-by-4 Outputs for:

- Point to Point/Multipoint Radio
- Test Equipment & Industrial Controls
- SATCOM
- Military End-Use

Functional Diagram



Features

- Dual Output: $F_o = 8.45 - 9.55$ GHz
 $F_o/2 = 4.225 - 4.775$ GHz
- Pout: +13 dBm
- Phase Noise: -116 dBc/Hz @100 kHz Typ.
- No External Resonator Needed
- 32 Lead 5x5mm SMT Package: 25mm²

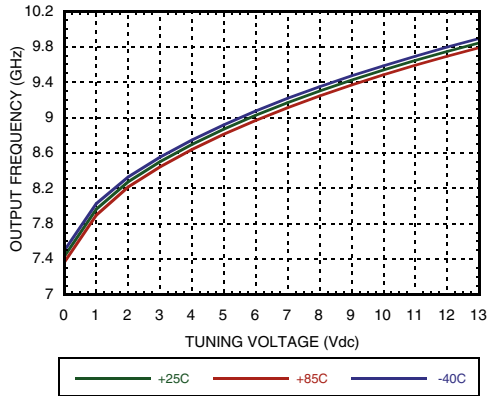
General Description

The HMC510LP5 & HMC510LP5E are GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCOs. The HMC510LP5 & HMC510LP5E integrate resonators, negative resistance devices, varactor diodes and feature half frequency and divide-by-4 outputs. The VCO's phase noise performance is excellent over temperature, shock, and process due to the oscillator's monolithic structure. Power output is +13 dBm typical from a +5V supply voltage. The prescaler and RF/2 functions can be disabled to conserve current if not required. The voltage controlled oscillator is packaged in a leadless QFN 5x5 mm surface mount package, and requires no external matching components.

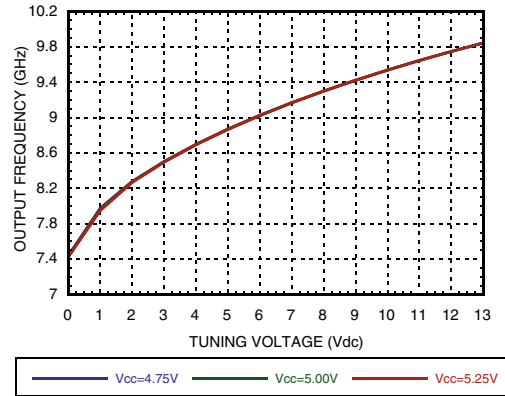
Electrical Specifications, $T_A = +25^\circ C$, $V_{cc} (Dig)$, $V_{cc} (Amp)$, $V_{cc} (RF) = +5V$

Parameter	Min.	Typ.	Max.	Units	
Frequency Range	F_o $F_o/2$	8.45 - 9.55 4.225 - 4.775		GHz GHz	
Power Output	RFOUT RFOUT/2 RFOUT/4	+10 +8 -8	+15 +14 -4	dBm dBm dBm	
SSB Phase Noise @ 100 kHz Offset, Vtune= +5V @ RFOUT		-116		dBc/Hz	
Tune Voltage	Vtune	2	13	V	
Supply Current	$I_{cc}(Dig) + I_{cc}(Amp) + I_{cc}(RF)$	270	315	360	mA
Tune Port Leakage Current (Vtune= 13V)			10	μA	
Output Return Loss		2		dB	
Harmonics/Subharmonics	1/2 2nd 3rd		40 15 40	dBc dBc dBc	
Pulling (into a 2.0:1 VSWR)		6		MHz pp	
Pushing @ Vtune= 5V		20		MHz/V	
Frequency Drift Rate		0.8		MHz/ $^\circ C$	

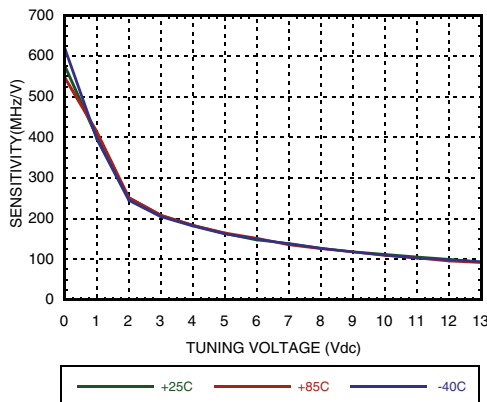
Frequency vs. Tuning Voltage, Vcc = +5V



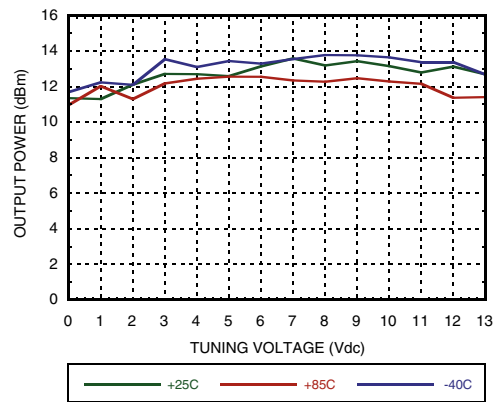
Frequency vs. Tuning Voltage, T = 25°C



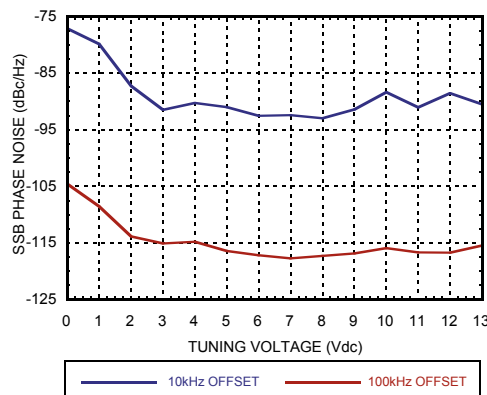
Sensitivity vs. Tuning Voltage, Vcc = +5V



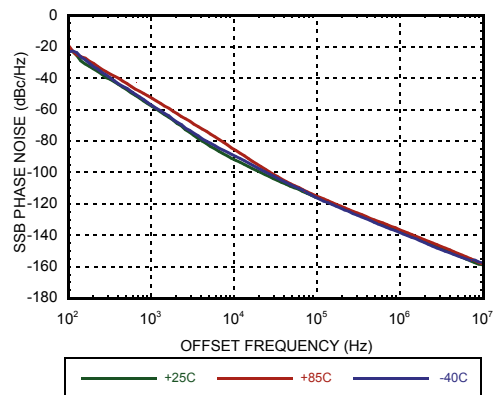
Output Power vs. Tuning Voltage, Vcc = +5V



SSB Phase Noise vs. Tuning Voltage



SSB Phase Noise @ Vtune = +5V

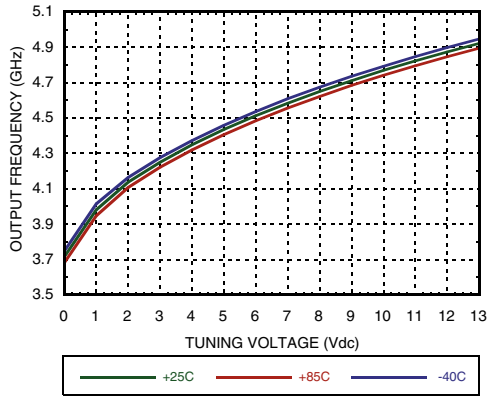




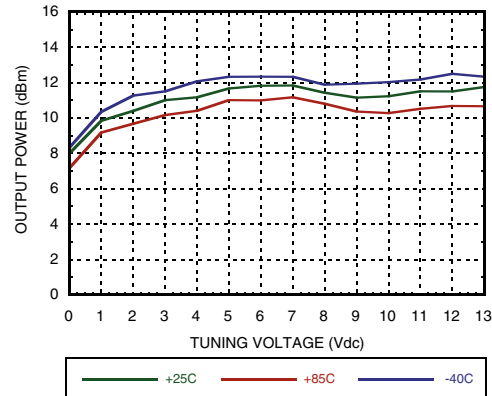
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VCOS WITH FO/2 OUTPUT - SMT

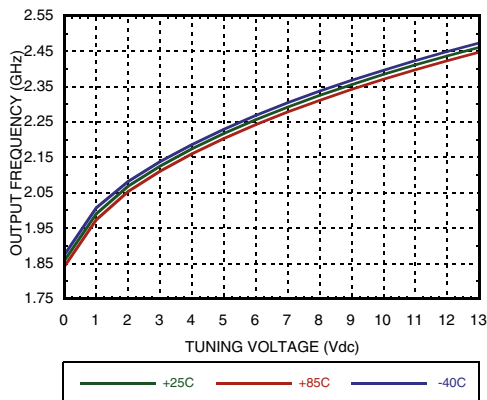
RFOUT/2 Frequency vs. Tuning Voltage, Vcc = +5V



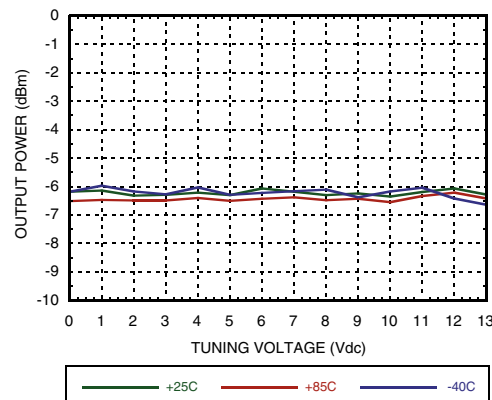
RFOUT/2 Output Power vs. Tuning Voltage, Vcc = +5V



Divide-by-4 Frequency vs. Tuning Voltage, Vcc = +5V



Divide-by-4 Output Power vs. Tuning Voltage, Vcc = +5V



Absolute Maximum Ratings

Vcc(Dig), Vcc(Amp), Vcc(RF)	+5.5 Vdc
Vtune	0 to +15V
Storage Temperature	-65 to +150 °C
ESD Sensitivity (HBM)	Class 1A

Reliability Information

Junction Temperature To Maintain 1 Million Hour MTTF	135 °C
Nominal Junction Temperature (T=85 °C)	121.2 °C
Thermal Resistance (junction to ground paddle)	23 °C/W
Operating Temperature	-40 to +85 °C

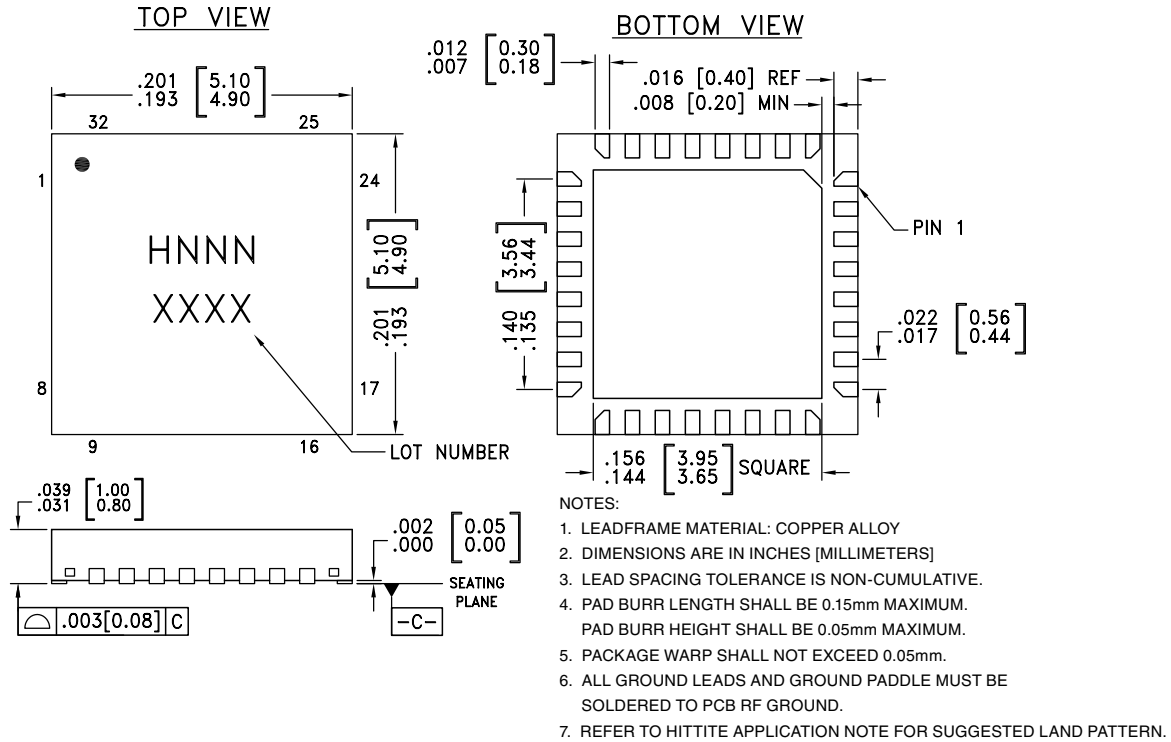


**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Typical Supply Current vs. Vcc

Vcc (V)	Icc (mA)
4.75	290
5.00	315
5.25	340

Note: VCO will operate over full voltage range shown above.

Outline Drawing

Package Information

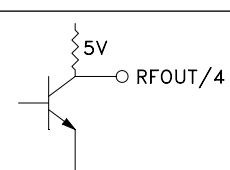
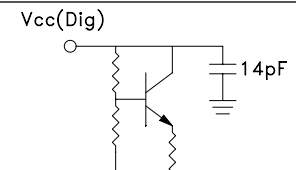
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC510LP5	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL3 ^[1]	H510 XXXX
HMC510LP5E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL3 ^[2]	H510 XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1-3, 8-10, 13-18, 20, 22-28, 30-32	N/C	No Connection. These pins may be connected to RF/DC ground. Performance will not be affected.	
4	RFOUT/4	Divide-by-4 output. DC block required.	
6	Vcc (Dig)	Supply voltage for prescaler. If prescaler is not required, this pin may be left open to conserve approximately 65 mA of current.	

For price, delivery and to place orders: Hittite Microwave Corporation, 2 Elizabeth Drive, Chelmsford, MA 01824

Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

Application Support: Phone: 978-250-3343 or apps@hittite.com

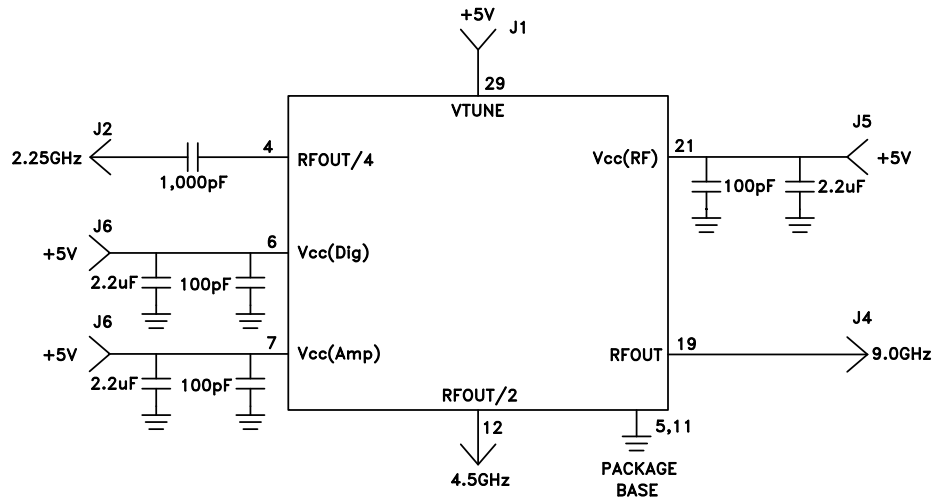


MMIC VCO WITH HALF FREQUENCY OUTPUT 8.45 - 9.55 GHz

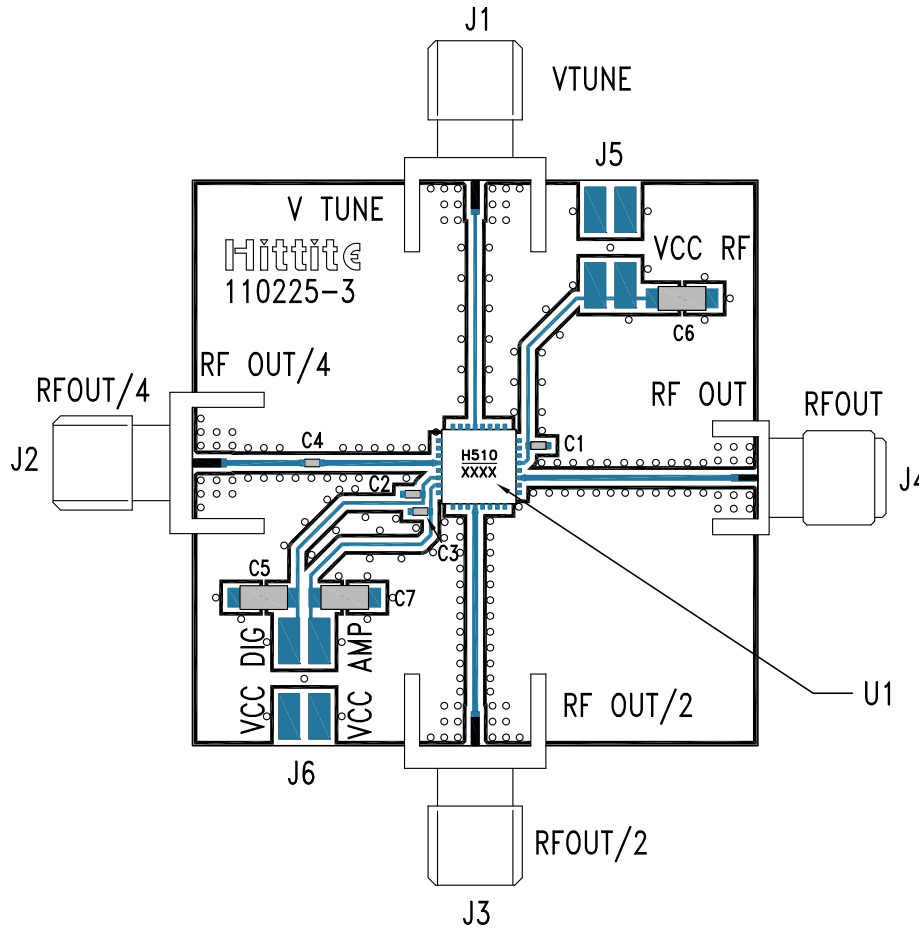
Pin Descriptions

Pin Number	Function	Description	Interface Schematic
7	Vcc (Amp)	Supply voltage, for RFOUT/2 output. If RFOUT/2 is not required, this pin may be left open to conserve approximately 30 mA of current.	
12	RFOUT/2	Half frequency output (AC coupled).	
19	RF OUT	RF output (AC coupled).	
21	Vcc (RF)	Supply Voltage, +5V	
29	VTUNE	Control voltage and modulation input. Modulation bandwidth dependent on drive source impedance. See "Determining the FM Bandwidth of a Wideband Varactor Tuned VCO" application note.	
5, 11, Paddle	GND	Package bottom has an exposed metal paddle that must be connected to RF/DC ground.	

Typical Application Circuit



Evaluation PCB



List of Materials for Evaluation PCB 110227 [1]

Item	Description
J1 - J4	PCB Mount SMA RF Connector
J5 - J6	2 mm DC Header
C1 - C3	100 pF Capacitor, 0402 Pkg.
C4	1,000 pF Capacitor, 0402 Pkg.
C5 - C7	2.2 μF Tantalum Capacitor
U1	HMC510LP5 / HMC510LP5E VCO
PCB [2]	110225 Eval Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and backside ground paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.